



50Ω TERMINATED    3 GHz    SMA    N/O    S.P.12T. SWITCH

OPTIONS : INDICATOR / TTL DRIVE / SUPP.DIODES

**R F CHARACTERISTICS**

NUMBER OF WAYS : 12  
 FREQUENCY RANGE : 0 - 3 GHz  
 IMPEDANCE : 50 Ohms

FREQUENCY (GHz)	0 - 3
V.S.W.R <=	1.20
INSERT. LOSS <=	0.20 dB
ISOLATION >=	80 dB
AVER. POWER (*)	120 W

TERMINATION IMPEDANCE : 50 Ohms  
 TERMINATION AVG. POWER AT 25°C : 1 W per termination  
 3 W total power

**ELECTRICAL CHARACTERISTICS**

ACTUATOR : NORMALLY OPEN  
 NOMINAL CURRENT AT 25°C (±10%) : 250 mA  
 ACTUATOR VOLTAGE (Vcc) : 12V (10.2 to 13V) / NEGATIVE COMMON  
 TERMINALS : solder pins (250°C max./30 sec.)  
 INDICATOR RATING : 1 W / 30 V / 100 mA  
 TTL INPUTS (E) - High level : 2.2 to 5.5V / 800µA at 5V  
                                   - Low level : 0 to 0.8V / 20µA at 0.8V

**MECHANICAL CHARACTERISTICS**

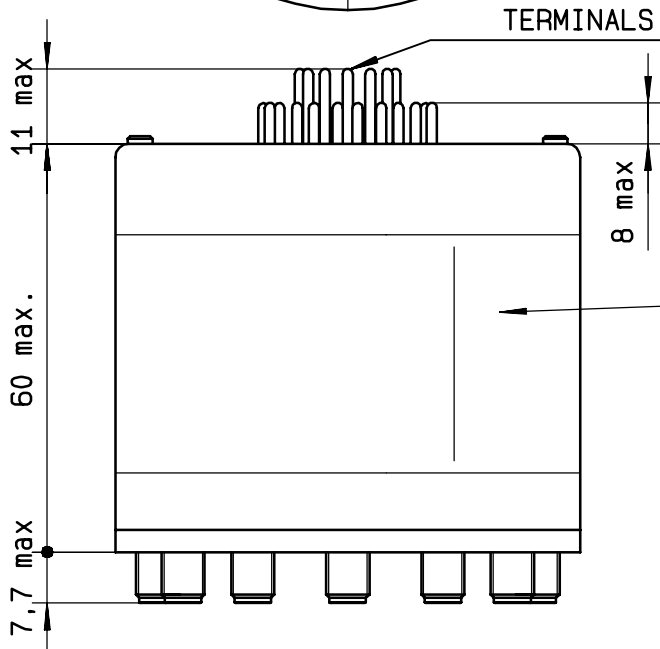
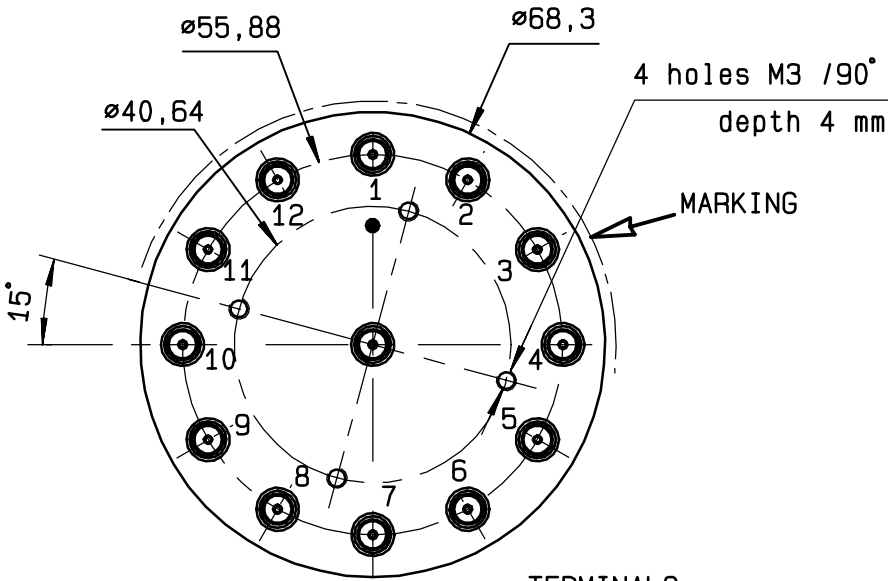
CONNECTORS : SMA female per MIL-C 39012  
 LIFE : 2.000.000 cycles per position  
 SWITCHING TIME (nominal voltage;25°C) : < 15 ms  
 CONSTRUCTION : splashproof  
 WEIGHT : < 400 g

**ENVIRONMENTAL CHARACTERISTICS**

OPERATING TEMPERATURE RANGE (°C) : -40 , +85  
 STORAGE TEMPERATURE RANGE (°C) : -55 , +85

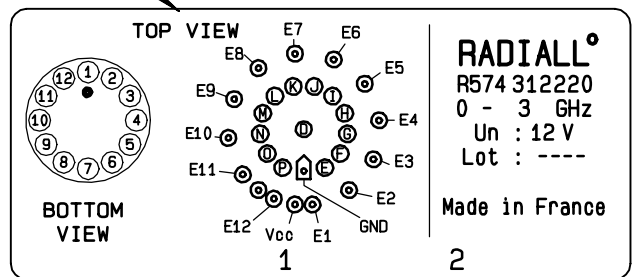
(\* : average power at 25°C per RF path)

This information is given as an indication. In the continual goal to improve our products, we reserve the right to make any modifications judged necessary

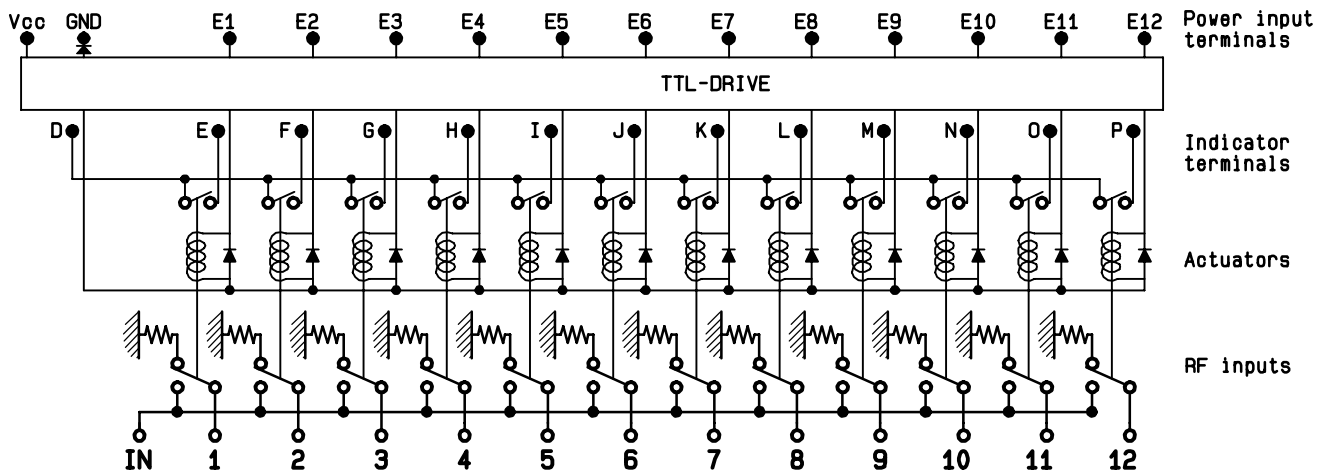


TTL input	RF continuity	Ind.
E1 = 1	IN ↔ 1	D.E
E2 = 1	IN ↔ 2	D.F
E3 = 1	IN ↔ 3	D.G
E4 = 1	IN ↔ 4	D.H
E5 = 1	IN ↔ 5	D.I
E6 = 1	IN ↔ 6	D.J
E7 = 1	IN ↔ 7	D.K
E8 = 1	IN ↔ 8	D.L
E9 = 1	IN ↔ 9	D.M
E10 = 1	IN ↔ 10	D.N
E11 = 1	IN ↔ 11	D.O
E12 = 1	IN ↔ 12	D.P

MARKING TOP VIEW (TERMINALS)



SCHEMATIC DIAGRAM



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